Applicant(s)	Roohpa~~r~~
Serial No.	09/627,770
Filing Date	July 28, 2000
Group Art Unit	~~2751~~ 2186
Examiner Name	Unknown
Attorney Docket No.	400.044US01

Title: SYNCHRONOUS FLASH MEMORY WITH ACCESSIBLE PAGE DURING WRITE

INFORMATION DISCLOSURE STATEMENT FORM PTO-1449

Sheet 1 of 1

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Examiner Signature	BR	Date Considered	9/30/03

*Examiner: Initial if citation considered, whether or not citation is in conformance with MPEP 609; Draw line through citation if not in conformance and not considered. Include copy of this form with next communication to applicant.

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